Structural Assessment of (Sub-)Monolayer Coatings in Device Processing at High Spatial Resolving Power by TOF-SIMS Tandem MS Imaging

Gregory L. Fisher¹

Whether in discovery research, failure analysis or reverse engineering, the objective is to ascertain the 2D/3D composition and structure of molecules in devices as a result of various processing steps. Most often there is neither sufficient background information nor reference spectra for substantiation of the analytical observations. Two case studies are described here wherein little guidance was provided but accurate and concrete answers were desired. In one case, a carbon residue was observed by Auger electron spectroscopic (AES) imaging of etched e⁻ beam-patterned structures, but the source of carbon was indeterminate. In a second case, molecules having ligands were patterned by a photolithography method and ostensibly loaded with catalytically active metals. Spatially resolved characterization was performed, but fell short of verifying the presence and structure of the intact metal-organic structures.

In this report, a general time-of-flight secondary ion mass spectrometry (TOF-SIMS) imaging method for unknown identification and structure elucidation is demonstrated, including the aforementioned examples. This method makes use of a TOF-TOF spectrometer designed for simultaneous TOF-SIMS (MS¹) imaging and tandem MS (MS²) imaging [1-4]. Ions for TOF-SIMS tandem MS imaging were produced by a Bi₃⁺ primary ion nanoprobe whereby MS¹ and MS² spectral data were generated from the same pixel in one duty cycle at a resolving power of 300 nm. Ion fluences were within the static limit (i.e. < 10^{13} Bi₃⁺/cm²) for nondestructive analysis, even where multiple analyses were conducted at the same position of the sample. Tandem MS peak attributions were made to a calculated mass accuracy ($\Delta_{m/z}$) of ≈ 1 ppm which provides confidence in the accuracy of the molecular identifications.

In the first example, TOF-SIMS tandem MS imaging was applied to characterize the carbon-containing residues of the lithography-patterned and etched structures (Figure 1). Several sets of peaks were observed at m/z > 150 in the MS¹ spectra. It was established and verified by tandem MS imaging that the carbon observed by AES imaging on the patterned sidewalls arose from two fatty acid (FA) contaminants; specifically, the [M-H]⁻ ions of FA(12:0) and FA(16:0) were identified. Further, a $\approx 2:1$ ratio of FA(12:0) to FA(16:0) was calculated. The high m/z peaks, detected only on the Cu-plated surfaces, were attributed to metal-organic complexes of Cu with the fatty acids. In the positive ion polarity, FACu₂⁺ and FA₂Cu₃⁺ ions were identified; in the negative ion polarity, FA⁻ and FA₂Cu⁻ ions were identified. In each case, a natural Cu isotope composition was confirmed.

TOF-SIMS tandem MS imaging was also employed to confirm the presence and elucidate the structure of metal-organic ligands of Au, Pd or Pt atoms attached to bipyridine or triphenylphosphine within patterned monolayer films (Figure 2). Metal atom loading was achieved after monolayer immobilization [5]. The pattern areas were readily observed based on the atomic metal ion signatures. There were a number of MS^1 precursor ions potentially related to the metal-organic ligands based on the m/z values lying in the anticipated range for the target structures. The 2D distribution and structure of complexed bipyridine and triphenylphosphine ligands, together with observing the natural isotope distribution of the metals, was achieved by tandem MS imaging [6].

^{1.} Physical Electronics, Chanhassen, Minnesota, USA.

References:

- [1] GL Fisher et al., Anal. Chem. **88** (2016), p. 6433.
- [2] GL Fisher et al., Microscop. Microanal. 23 (2017), p. 843.
- [3] CE Chini et al, Biointerphases **13** (2018), p. 03B409.
- [4] T Fu et al., Nature Sci. Rep. (2018) accepted December 06, 2018.
- [5] R Müller et al., Chemistry (2018). DOI: 10.1002/chem.201803966.
- [6] R Müller and A Welle at Karlsruhe Institute of Technology (KIT) and C Barner-Kowollik at Queensland University of Technology (QUB) are acknowledged for providing the samples for analysis.

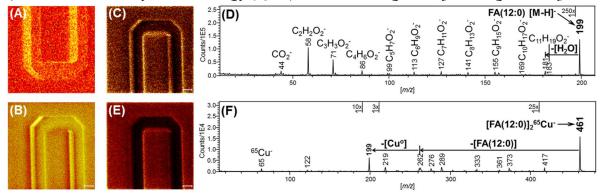


Figure 1. (A) An AES map of carbon on an e⁻ beam patterned device structure after etching. The signal of carbon is elevated on the sidewalls of the structure where there is no Cu plating. The image area is 70 μm x 70 μm, and the image is rotated 180° to display the same sidewall illumination as viewed in the TOF-SIMS images. (B) An MS¹ ion image of SiCO₂H⁻ (m/z 73) in a 100 μm x 100 μm area of the e⁻ beam patterned device structure after etching. This image and others, e.g. C₂⁻ (m/z 24) and SiCH⁻ (m/z 41), show elevated carbon moieties at the sidewalls of the structure. (C) An MS² ion image of m/z 199 ions, identified as FA(12:0) [M-H]⁻ by the product ion spectrum in panel (D), indicating a greater abundance at the sidewalls of the structure. (E) An MS² ion image of m/z 461 ions, identified as [FA(12:0)]₂⁶⁵Cu⁻ by the product ion spectrum in panel (F), revealing that the metal-organic complex is present only at the Cuplated surface of the device structure.

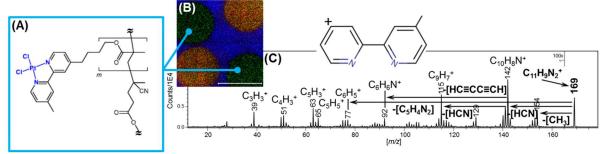


Figure 2. (A) Illustration of a metal-organic ligand of the bi-functionalized monolayer and where it is observed within the imaged area. (B) False color overlay ion image of the bi-functionalized monolayer composed of Pd⁺ (MS¹ m/z 106, red), C₁₁H₉N₂⁺ (MS² m/z 169, green) and SiH⁺ (MS¹ m/z 29, blue). The scale marker is 1 mm. (C) An MS² product ion spectrum of the presumed 4-methyl-2,2'-bipyridine moiety of the metal-organic ligand depicted in panel (A) which was acquired simultaneously with the image data shown in panel (B). The product ion spectrum of the m/z 169 precursor ion (inset) is consistent with the 4-methyl-2,2'-bipyridine composition and the peak attributions are made to a calculated mass accuracy ($\Delta_{m/z}$) of +1.31 ppm.